- State-of-the-Art BiCMOS Design Significantly Reduces I_{CCZ}
- Bus Transceivers/Registers
- Independent Registers and Enables for A and B Buses
- Multiplexed Real-Time and Stored Data
- ESD Protection Exceeds JESD 22
  – 2000-V Human-Body Model (A114-A)
  – 200-V Machine Model (A115-A)

SN54BCT646 . . . JT OR W PACKAGE
SN74BCT646 . . . DW OR NT PACKAGE
(TOP VIEW)

CLKAB	1 24	V_{CC}
SAB	2 23	CLKBA
DIR	3 22	SBA
A1	4 21	$\overline{OE}$
A2	5 20	B1
A3	6 19	B2
A4	7 18	B3
A5	8 17	B4
A6	9 16	B5
A7	10 15	B6
A8	11 14	B7
GND	12 13	B8
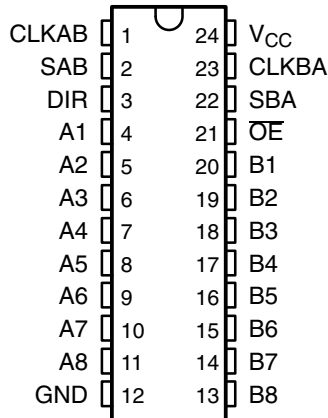
SN54BCT646 . . . FK PACKAGE
(TOP VIEW)

Pins (top, left to right): DIR, SAB, CLKAB, NC, V_{CC}, CLKBA, SBA (4 3 2 1 28 27 26)

A1	5 25	$\overline{OE}$
A2	6 24	B1
A3	7 23	B2
NC	8 22	NC
A4	9 21	B3
A5	10 20	B4
A6	11 19	B5

Pins (bottom, left to right): A7, A8, GND, NC, B8, B7, B6 (12 13 14 15 16 17 18)
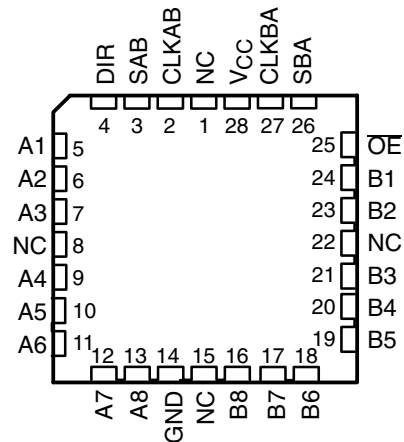
NC – No internal connection

description/ordering information

These devices consist of bus transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus is clocked into the registers on the low-to-high transition of the appropriate clock (CLKAB or CLKBA) input. Figure 1 illustrates the four fundamental bus-management functions that can be performed with the 'BCT646 devices.

Output-enable ($\overline{OE}$) and direction-control (DIR) inputs are provided to control the transceiver functions. In the transceiver mode, data present at the high-impedance port can be stored in either register or in both.

The select-control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode) data. The direction control (DIR) determines which bus will receive data when $\overline{OE}$ is low. In the isolation mode ($\overline{OE}$ high), A data can be stored in one register and/or B data can be stored in the other register.

ORDERING INFORMATION

T_A	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	PDIP – NT	Tube	SN74BCT646NT	SN74BCT646NT
	SOIC – DW	Tube	SN74BCT646DW	BCT646
		Tape and reel	SN74BCT646DWR	
–55°C to 125°C	CDIP – JT	Tube	SNJ54BCT646JT	SNJ54BCT646JT
	CFP – W	Tube	SNJ54BCT646W	SNJ54BCT646W
	LCCC – FK	Tube	SNJ54BCT646FK	SNJ54BCT646FK

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TEXAS INSTRUMENTS

description/ordering information(continued)

When an output function is disabled, the input function still is enabled and can be used to store and transmit data. Only one of the two buses, A or B, can be driven at a time.
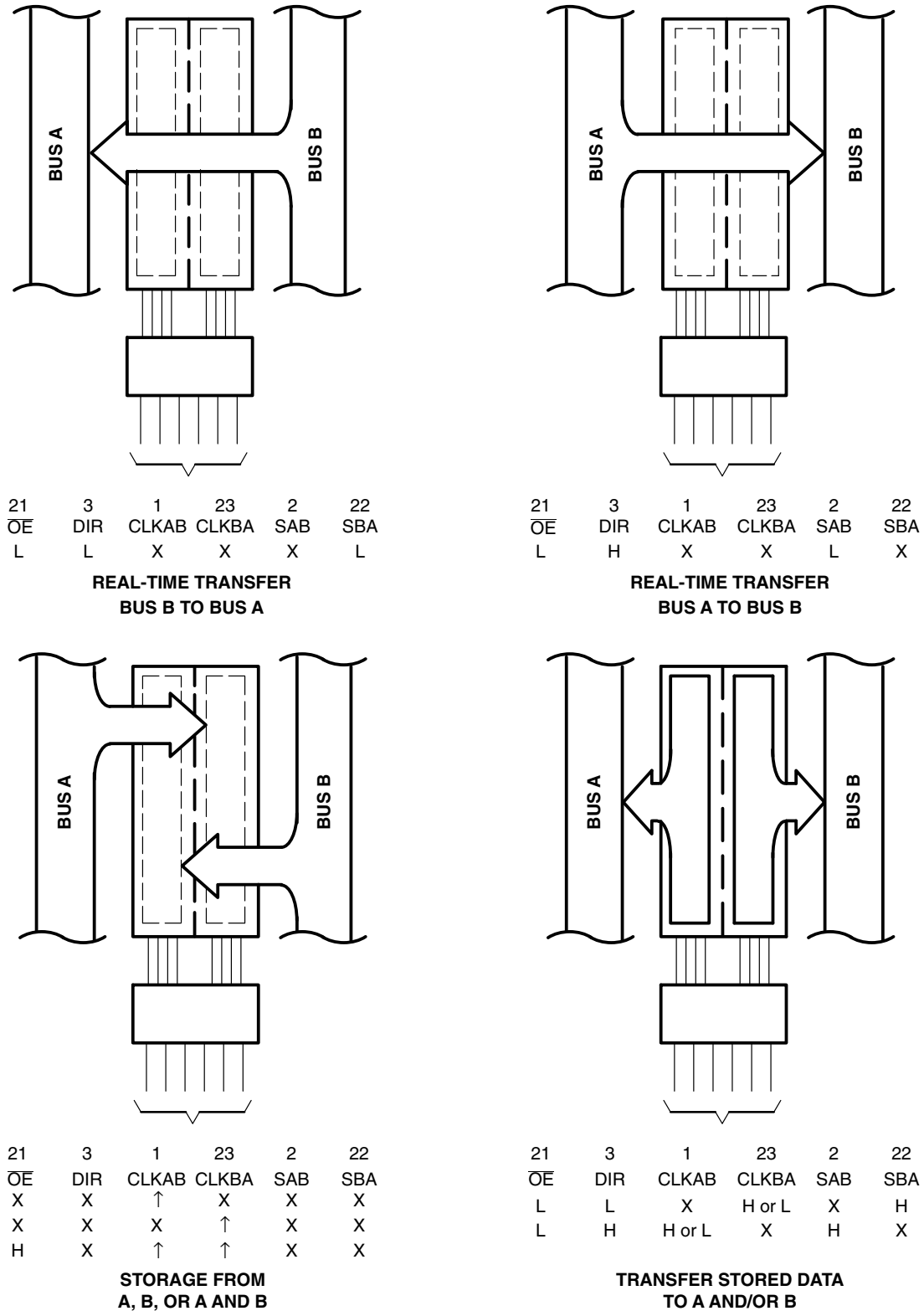
To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

21	3	1	23	2	22
$\overline{OE}$	DIR	CLKAB	CLKBA	SAB	SBA
L	L	X	X	X	L

REAL-TIME TRANSFER
BUS B TO BUS A

21	3	1	23	2	22
$\overline{OE}$	DIR	CLKAB	CLKBA	SAB	SBA
L	H	X	X	L	X

REAL-TIME TRANSFER
BUS A TO BUS B

21	3	1	23	2	22
$\overline{OE}$	DIR	CLKAB	CLKBA	SAB	SBA
X	X	↑	X	X	X
X	X	X	↑	X	X
H	X	↑	↑	X	X

STORAGE FROM
A, B, OR A AND B

21	3	1	23	2	22
$\overline{OE}$	DIR	CLKAB	CLKBA	SAB	SBA
L	L	X	H or L	X	H
L	H	H or L	X	H	X

TRANSFER STORED DATA
TO A AND/OR B

Pin numbers shown are for the DW, JT, NT, and W packages.

Figure 1. Bus-Management Functions

SN54BCT646, SN74BCT646
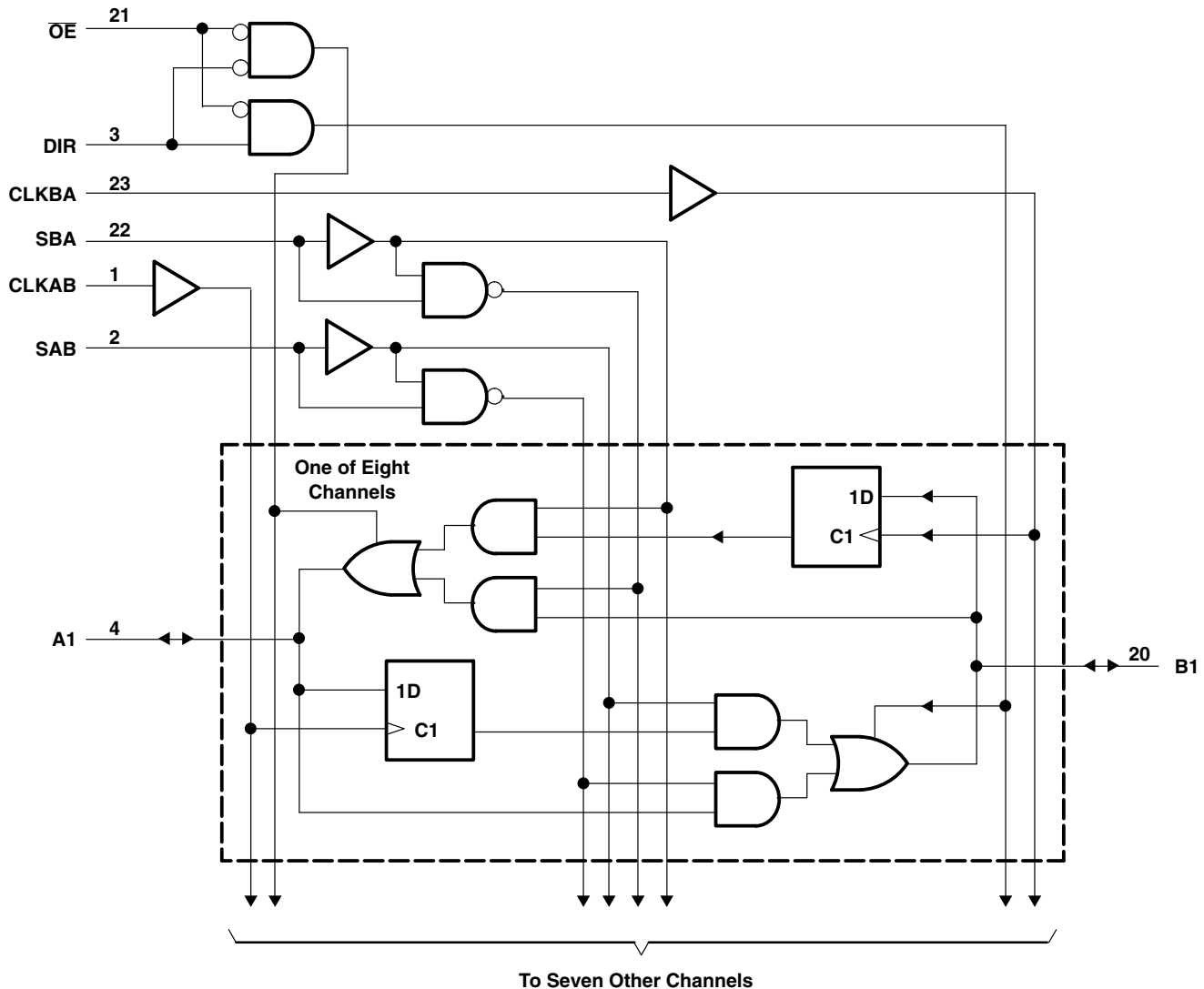# OCTAL BUS TRANSCEIVERS AND REGISTERS
WITH 3-STATE OUTPUTS

SCBS037D – AUGUST 1989 – REVISED MAY 2004

FUNCTION TABLE

INPUTS						DATA I/O		OPERATION OR FUNCTION
$\overline{OE}$	DIR	CLKAB	CLKBA	SAB	SBA	A1 THRU A8	B1 THRU B8	
X	X	↑	X	X	X	Input	Unspecified[†]	Store A, B unspecified[†]
X	X	X	↑	X	X	Unspecified[†]	Input	Store B, A unspecified[†]
H	X	↑	↑	X	X	Input	Input	Store A and B data
H	X	H or L	H or L	X	X	Input disabled	Input disabled	Isolation, hold storage
L	L	X	X	X	L	Output	Input	Real-time B data to A bus
L	L	X	H or L	X	H	Output	Input	Stored B data to A bus
L	H	X	X	L	X	Input	Output	Real-time A data to B bus
L	H	H or L	X	H	X	Input	Output	Stored A data to B bus

[†] The data output functions can be enabled or disabled by various signals at the $\overline{OE}$ and DIR inputs. Data input functions always are enabled, i.e., data at the bus pins is stored on every low-to-high transition of the clock inputs.

logic diagram (positive logic)

To Seven Other Channels

Pin numbers shown are for the DW, JT, NT, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . −0.5 V to 7 V

Input voltage range: Control inputs (see Note 1) . . . . −0.5 V to 7 V

I/O ports (see Note 1) . . . . −0.5 V to 5.5 V

Voltage range applied to any output in the disabled or power-off state, V_O . . . . −0.5 V to 7 V

Voltage range applied to any output in the high state, V_O . . . . −0.5 V to V_{CC}

Current into any output in the low state: SN54BCT646 . . . . 96 mA

SN74BCT646 . . . . 128 mA

Package thermal impedance, θ_{JA} (see Note 2): DW package . . . . 46°C/W

(see Note 3): NT package . . . . 67°C/W

Storage temperature range, T_{stg} . . . . −65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The package thermal impedance is calculated in accordance with JESD 51-7.
3. The package thermal impedance is calculated in accordance with JESD 51-3.

recommended operating conditions (see Note 4)

		SN54BCT646			SN74BCT646			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.8			0.8	V
I_{IK}	Input clamp current			−18			−18	mA
I_{OH}	High-level output current			−12			−15	mA
I_{OL}	Low-level output current			48			64	mA
T_A	Operating free-air temperature	−55		125	0		70	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54BCT646			SN74BCT646			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
V_{IK}		V_{CC} = 4.5 V,	I_I = −18 mA			−1.2			−1.2	V
V_{OH}		V_{CC} = 4.5 V	I_{OH} = −3 mA	2.4	3.3		2.4	3.3		V
			I_{OH} = −12 mA	2	3.2					
			I_{OH} = −15 mA				2	3.1		
V_{OL}		V_{CC} = 4.5 V	I_{OL} = 48 mA		0.38	0.55				V
			I_{OL} = 64 mA					0.42	0.55	
I_I	A or B port	V_{CC} = 5.5 V,	V_I = 5.5 V			1			1	mA
	Control inputs					1			1	
I_{IH}‡	A or B port	V_{CC} = 5.5 V,	V_I = 2.7 V			70			70	μA
	Control inputs					20			20	
I_{IL}‡	A or B port	V_{CC} = 5.5 V,	V_I = 0.5 V			−0.7			−0.7	mA
	Control inputs					−0.7			−0.7	
I_{OS}§		V_{CC} = 5.5 V,	V_O = 0	−100		−225	−100		−225	mA
I_{CCL}	A or B port	V_{CC} = 5.5 V,	V_I = GND		42	67		42	67	mA
I_{CCH}	A or B port	V_{CC} = 5.5 V,	V_I = 4.5 V		5.6	9		5.6	9	mA
I_{CCZ}	A or B port	V_{CC} = 5.5 V,	V_I = GND		10	16		10	16	mA
C_i	Control inputs	V_{CC} = 5 V,	V_I = 2.5 V or 0.5 V		6			6		pF
C_{io}	A or B port	V_{CC} = 5 V,	V_O = 2.5 V or 0.5 V		12			14		pF

† All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.
§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

		V_{CC} = 5 V, T_A = 25°C		SN54BCT646		SN7BCT646		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
f_{clock}	Clock frequency		83		83		83	MHz
t_w	Pulse duration, CLK high or low	6		6		6		ns
t_{su}	Setup time, A or B before CLKAB↑ or CLKBA↑	6		7		6		ns
t_h	Hold time, A or B after CLKAB↑ or CLKBA↑	0.5		0.5		0.5		ns

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 2)

| PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 5 V, T_A = 25°C			SN54BCT646		SN74BCT646		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
f_{max}			83			83		83		MHz
t_{PLH}	CLKBA or CLKAB	A or B	3.6	7	9.4	3.6	12.4	3.6	11.2	ns
t_{PHL}			3.9	7	9.2	3.9	11.5	3.9	10.6	
t_{PLH}	A or B	B or A	3.1	6	8.1	3.1	11.1	3.1	9.5	ns
t_{PHL}			3.7	6.8	8.9	3.7	12.1	3.7	10.5	
t_{PLH}	SAB or SBA[†] (with A or B high)	A or B	4.5	8.8	11.2	4.5	15.2	4.5	13.8	ns
t_{PHL}			3.3	6	8.1	3.3	9.8	3.3	9.1	
t_{PLH}	SAB or SBA[†] (with A or B low)	A or B	3.9	7.7	10.2	3.9	13.3	3.9	12	ns
t_{PHL}			4.7	8.3	10.8	4.7	13.7	4.7	12.9	
t_{PZH}	$\overline{OE}$	A or B	4	7.9	10.7	4	14	4	13.2	ns
t_{PZL}			4.6	8.8	11.8	4.6	15.4	4.6	14.4	
t_{PHZ}	$\overline{OE}$	A or B	4	7.2	9.4	4	12	4	10.9	ns
t_{PLZ}			3.4	7	9.3	3.4	11.6	3.4	10.5	
t_{PZH}	DIR	A or B	2.8	7.8	10.7	2.8	14	2.8	13.1	ns
t_{PZL}			3.8	8.9	11.9	3.8	15.6	3.8	14.6	
t_{PHZ}	DIR	A or B	3.8	8.4	10.7	3.8	13.2	3.8	12.6	ns
t_{PLZ}			3.2	7.3	9.9	3.2	12.6	3.2	11.8	

[†] These parameters are measured with the internal output state of the storage register opposite that of the bus input.
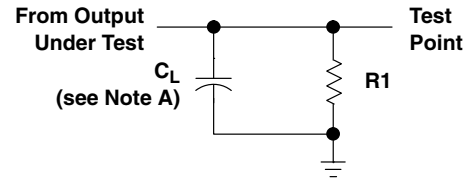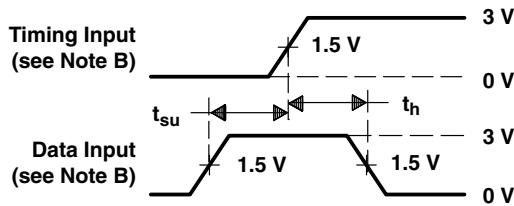
TEXAS INSTRUMENTS

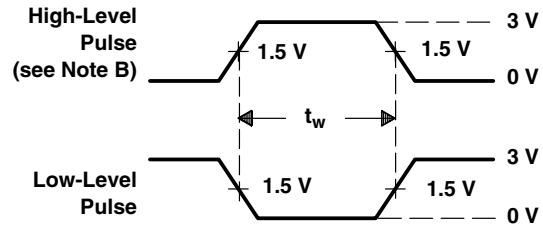## PARAMETER MEASUREMENT INFORMATION
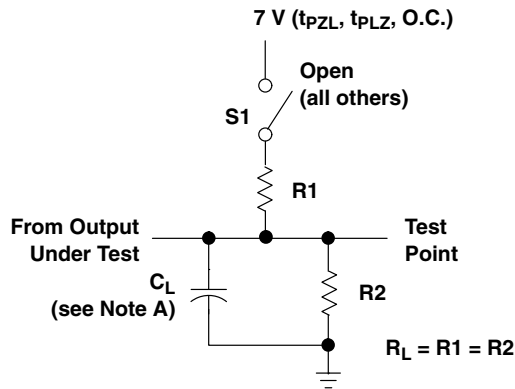
LOAD CIRCUIT FOR
3-STATE AND OPEN-COLLECTOR OUTPUTS
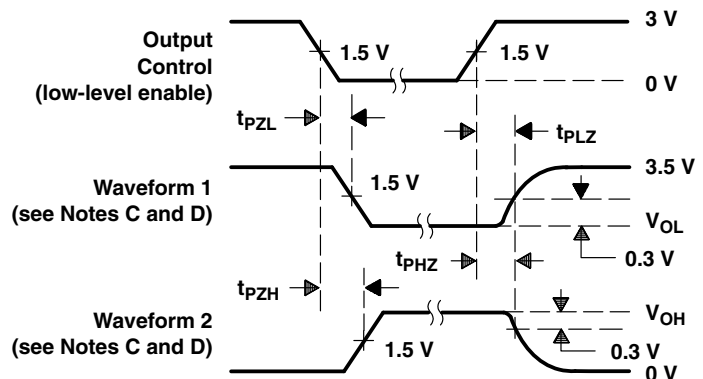
LOAD CIRCUIT FOR
TOTEM-POLE OUTPUTS

VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES

VOLTAGE WAVEFORMS
PULSE DURATION
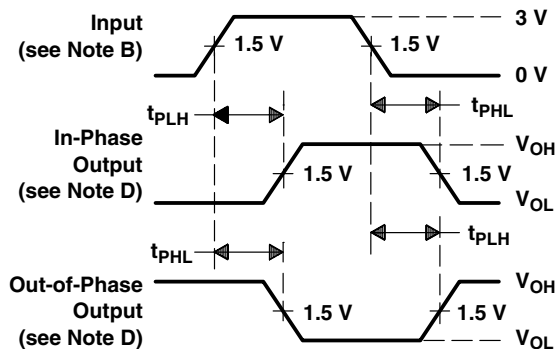
VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES (see Note D)

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES, 3-STATE OUTPUTS

NOTES: A. C_L includes probe and jig capacitance.
B. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $t_r = t_f ≤ 2.5$ ns, duty cycle = 50%.
C. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
D. The outputs are measured one at a time, with one transition per measurement.
E. When measuring propagation delay times of 3-state outputs, switch S1 is open.
F. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9155501M3A	ACTIVE	LCCC	FK	28	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9155501M3A SNJ54BCT 646FK	Samples
5962-9155501MLA	ACTIVE	CDIP	JT	24	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9155501MLA SNJ54BCT646JT	Samples
SN74BCT646DW	ACTIVE	SOIC	DW	24	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	BCT646	Samples
SNJ54BCT646FK	ACTIVE	LCCC	FK	28	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9155501M3A SNJ54BCT 646FK	Samples
SNJ54BCT646JT	ACTIVE	CDIP	JT	24	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9155501MLA SNJ54BCT646JT	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54BCT646, SN74BCT646 :

- Catalog : SN74BCT646

- Military : SN54BCT646

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

- Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

TUBE

T - Tube height

L - Tube length

W - Tube width

B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74BCT646DW	DW	SOIC	24	25	506.98	12.7	4826	6.6

JT (R-GDIP-T**)　　　　　　　　　　　　　　　　　　　**CERAMIC DUAL-IN-LINE**

24 LEADS SHOWN

	PINS **	24	28
DIM			
A MAX		1.280 (32,51)	1.460 (37,08)
A MIN		1.240 (31,50)	1.440 (36,58)
B MAX		0.300 (7,62)	0.291 (7,39)
B MIN		0.245 (6,22)	0.285 (7,24)

4040110/C 08/96

NOTES:　A.　All linear dimensions are in inches (millimeters).
　　　　　B.　This drawing is subject to change without notice.
　　　　　C.　This package can be hermetically sealed with a ceramic lid using glass frit.
　　　　　D.　Index point is provided on cap for terminal identification.
　　　　　E.　Falls within MIL STD 1835 GDIP3-T24, GDIP4-T28, and JEDEC MO-058 AA, MO-058 AB

FK (S−CQCC−N**)   LEADLESS CERAMIC CHIP CARRIER
28 TERMINAL SHOWN

NO. OF TERMINALS **	A		B	
	MIN	MAX	MIN	MAX
20	0.342 (8,69)	0.358 (9,09)	0.307 (7,80)	0.358 (9,09)
28	0.442 (11,23)	0.458 (11,63)	0.406 (10,31)	0.458 (11,63)
44	0.640 (16,26)	0.660 (16,76)	0.495 (12,58)	0.560 (14,22)
52	0.740 (18,78)	0.761 (19,32)	0.495 (12,58)	0.560 (14,22)
68	0.938 (23,83)	0.962 (24,43)	0.850 (21,6)	0.858 (21,8)
84	1.141 (28,99)	1.165 (29,59)	1.047 (26,6)	1.063 (27,0)

4040140/D 01/11

NOTES: A.   All linear dimensions are in inches (millimeters).
          B.   This drawing is subject to change without notice.
          C.   This package can be hermetically sealed with a metal lid.
          D.   Falls within JEDEC MS−004

TEXAS
INSTRUMENTS
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DW (R−PDSO−G24)   PLASTIC SMALL OUTLINE

0.614 (15,60)
0.598 (15,20)

24   13

0.419 (10,63)
0.393 (9,97)

0.299 (7,60)
0.291 (7,40)

1   12

Pin 1
Index Area

0.050 (1,27)

0.020 (0,51)
0.012 (0,31)

⊕ | 0.010 (0,25) | Ⓜ

0.104 (2,65) Max

0.012 (0,30)
0.004 (0,10)

0.013 (0,33)
0.008 (0,20)

⌂ | 0.004 (0,10)

Gauge Plane

Seating Plane

0.010 (0,25)   0°−8°

0.050 (1,27)
0.016 (0,40)

4040000−5/G 01/11

NOTES: A.   All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M−1994.
         B.   This drawing is subject to change without notice.
         C.   Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
         D.   Falls within JEDEC MS−013 variation AD.

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